SONY

Ver. 1.0

IMX347LQR

Diagonal 9.04 mm (Type 1/1.8) CMOS Solid-state Image Sensor with Square Pixel for Color Cameras

Description

The IMX347LQR is a diagonal 9.04 mm (Type 1/1.8) CMOS active pixel type solid-state image sensor with a square pixel array and 4.17 M effective pixels. This chip operates with analog 2.9 V, digital 1.2 V, and interface 1.8 V triple power supply, and has low power consumption. High sensitivity, low dark current and no smear are achieved through the adoption of R, G and B primary color mosaic filters. This chip features an electronic shutter with variable charge-integration time.

(Applications: Surveillance cameras, FA cameras, Industrial cameras)

Features

- ◆ CMOS active pixel type dots
- ◆ Built-in timing adjustment circuit, H/V driver and serial communication circuit
- ◆ Input frequency: 6 to 27 MHz / 37.125 MHz / 74.25 MHz
- ♦ Number of recommended recording pixels: 2688 (H) × 1520 (V) approx. 4.09 M pixels
- ◆ Readout mode

All-pixel scan mode

Window cropping mode

Vertical / Horizontal direction-normal / inverted readout mode

Readout rate

Maximum frame rate in All-pixel scan mode 2688 (H) × 1520 (V) A/D 10-bit : 90 frame/s

◆ High dynamic range (HDR) function

Multiple exposure HDR

Digital overlap HDR

- ◆ Variable-speed shutter function (resolution 1H units)
- ◆ 10-bit / 12-bit A/D converter
- ◆ CDS / PGA function

0 dB to 29.4 dB : Analog Gain 29.4 dB (step pitch 0.3 dB)

29.7 dB to 71.4 dB: Analog Gain 29.4 dB + Digital Gain 0.3 to 42 dB (step pitch 0.3 dB)

Supports I/O

CSI-2 serial data output (2 Lane / 4 Lane, RAW10 / RAW12 output)

◆ Recommended exit pupil distance: –30 mm to –∞



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Device Structure

◆ CMOS image sensor

♦ Image size

◆ Total number of pixels
♦ Number of effective pixels
A Number of active pixels
2712 (H) × 1538 (V) approx. 4.17 M pixels
2713 (H) × 1536 (V) approx. 4.17 M pixels

Number of active pixels
Number of recommended recording pixels
2712 (H) × 1536 (V) approx. 4.17 M pixels
2688 (H) × 1520 (V) approx. 4.09 M pixels

♦ Unit cell size 2.9 μm (H) × 2.9 μm (V)

◆ Optical black Horizontal (H) direction: Front 0 pixel, rear 0 pixel

Type 1/1.8

Vertical (V) direction: Front 13 pixels, rear 0 pixel

◆ Dummy Horizontal (H) direction: Front 0 pixel, rear 0 pixel

Vertical (V) direction: Front 0 pixel, rear 0 pixel

◆ Package 132 pin LGA

Image Sensor Characteristics

(Tj = 60 °C)

Item		Value	Remarks	
Sensitivity (F5.6)	Тур.	11092 Digit	1/30 s accumulation 12 bit converted value	
Saturation signal	Min.	3895 Digit	12 bit converted value	

Basic Drive Mode

Drive mode	Recommended number of recording pixels	Maximum frame rate [frame/s]	Output interface	ADC [bit]
All pixel	2688 (H) × 1520 (V) approx. 4.09 M pixels	90	CSI-2	10

